

10/565767

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OGOSH43USA

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:)	
)	Examiner:
Yuichiro Shindo)	
)	Group Art Unit:
Application No.:)	
)	
Corresponding International Filing No.:)	
PCT/JP2004/005389)	
)	
Filed: Herewith)	
)	
For: HIGHLY PURE HAFNIUM)	
MATERIAL, TARGET AND)	
THIN FILM COMPRISING THE)	
SAME AND METHOD FOR)	
PRODUCING HIGHLY PURE)	
HAFNIUM)	

Mail Stop PCT
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SECOND PRELIMINARY AMENDMENT

Sir:

Please amend the above-identified patent application as follows.

Amendments to the Specification begin on page two of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page three of this paper.

Remarks begin on page seven of this paper.